

N-Channel Enhancement Mode MOSFET

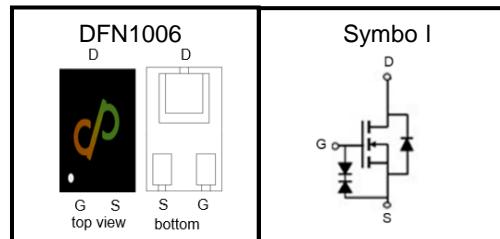
Feature

- Surface mount package
- Reliable and Rugged
- ROHS Compliant & Halogen-Free
- ESD Protection

Applications

- Small Signal Switch
- Load Switch

Pin Description



V_{DSS}	20	V
$R_{DS(ON)}\text{-Max}$	230	$\text{m}\Omega$
I_D	1.4	A

Absolute Maximum Ratings ($T_J=25^\circ\text{C}$ Unless Otherwise Noted)

Symbol	Parameter		Rating	Unit	
V_{DSS}	Drain-Source Voltage		20	V	
V_{GSS}			± 8		
T_J	Maximum Junction Temperature		150	$^\circ\text{C}$	
T_{STG}	Storage Temperature Range		-55 to 150	$^\circ\text{C}$	
I_S	Diode Continuous Forward Current		0.6	A	
$I_{DM}^{\text{(1)}}$	Pulse Drain Current Tested	$T_A=25^\circ\text{C}$	3.5	A	
I_D	Continuous Drain Current	$T_A=25^\circ\text{C}$	1.4	A	
		$T_A=70^\circ\text{C}$	1.1		
P_D	Maximum Power Dissipation	$T_A=25^\circ\text{C}$	0.7	W	
		$T_A=70^\circ\text{C}$	0.4		

Thermal Characteristics

Symbol	Parameter		Rating	Unit
$R_{\theta JA}^{\text{(2)}}$	Thermal Resistance-Junction to Ambient	Steady State	180	$^\circ\text{C/W}$

Note ① : Max. current is limited by junction temperature.

Note ② : Surface Mounted on 1in² FR-4 board with 1oz.

Electrical Characteristics ($T_J=25^\circ\text{C}$ Unless Otherwise Noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Static Electrical Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}, I_D=250\mu\text{A}$	20	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=16\text{V}, V_{GS}=0\text{V}$	-	-	1	μA
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	0.5	-	1	V
I_{GSS}	Gate Leakage Current	$V_{GS}=\pm 8\text{V}, V_{DS}=0\text{V}$	-	-	± 10	μA
$R_{DS(\text{ON})}^{(3)}$	Drain-Source On-state Resistance	$V_{GS}=4.5\text{V}, I_D=550\text{mA}$	-	190	230	$\text{m}\Omega$
		$V_{GS}=2.5\text{V}, I_D=450\text{mA}$	-	234	305	
		$V_{GS}=1.8\text{V}, I_D=350\text{mA}$	-	303	455	
g_{fs}	Forward Transconductance	$V_{DS}=5\text{V}, I_D=550\text{mA}$	-	1.7	-	S
Dynamic Characteristics ⁽⁴⁾						
C_{iss}	Input Capacitance	$V_{GS}=0\text{V}, V_{DS}=10\text{V}, \text{Freq.}=1\text{MHz}$	-	43	-	pF
C_{oss}	Output Capacitance		-	9	-	
C_{rss}	Reverse Transfer Capacitance		-	6	-	
$t_{d(\text{ON})}$	Turn-on Delay Time	$V_{DD}=10\text{V}, I_D=2\text{A}, V_{GS}=4.5\text{V}, R_{GEN}=6\Omega$	-	1.2	-	nS
t_r	Turn-on Rise Time		-	25	-	
$t_{d(\text{OFF})}$	Turn-off Delay Time		-	14	-	
t_f	Turn-off Fall Time		-	15	-	
Q_g	Total Gate Charge	$V_{DS}=10\text{V}, V_{GS}=2.5\text{V}, I_D=1\text{A}$	-	1.1	-	nC
Q_g	Total Gate Charge	$V_{DS}=10\text{V}, V_{GS}=4.5\text{V}, I_D=1\text{A}$	-	2	-	
Q_{gs}	Gate-Source Charge		-	0.3	-	
Q_{gd}	Gate-Drain Charge		-	0.3	-	
Source-Drain Characteristics						
$V_{SD}^{(3)}$	Diode Forward Voltage	$I_S=0.35\text{A}, V_{GS}=0\text{V}$	-	0.75	1.1	V
t_{rr}	Reverse Recovery Time	$I_F=1\text{A}, V_{GS}=0, dI_F/dt=100\text{A}/\mu\text{s}$	-	9	-	nS
Q_{rr}	Reverse Recovery Charge		-	1	-	nC

Note ⁽³⁾ : Pulse test (pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$).

Note ⁽⁴⁾ : Guaranteed by design, not subject to production testing.

Typical Characteristics

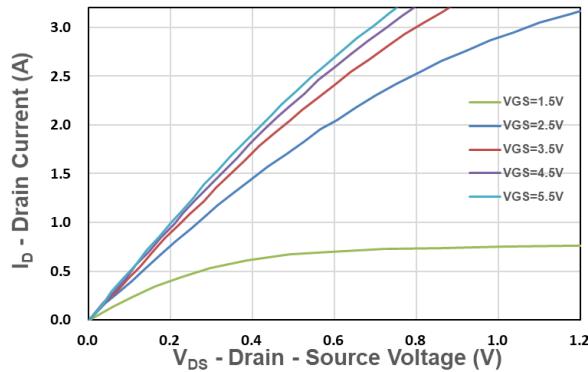


Figure 1. Output Characteristics

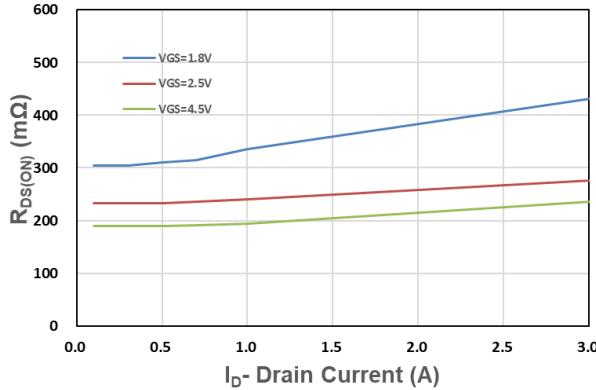


Figure 2. On-Resistance vs. I_D

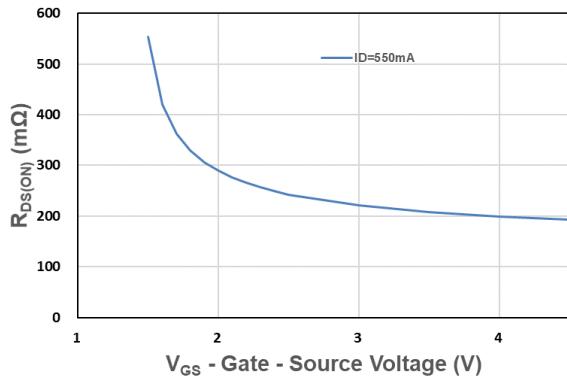


Figure 3. On-Resistance vs. V_{GS}

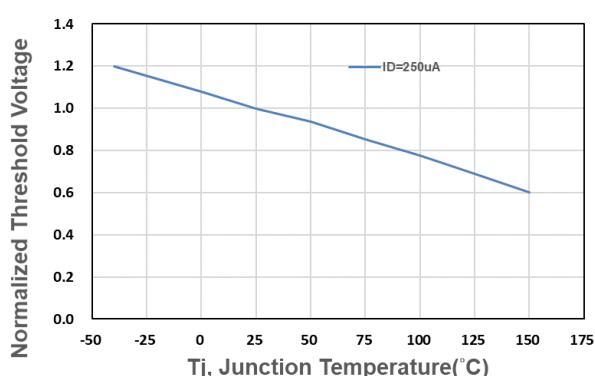


Figure 4. Gate Threshold Voltage

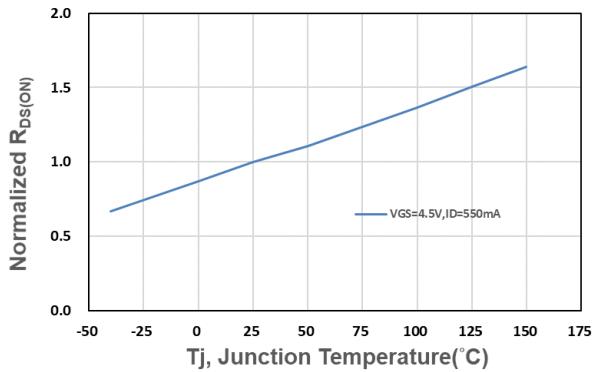


Figure 5. Drain-Source On Resistance

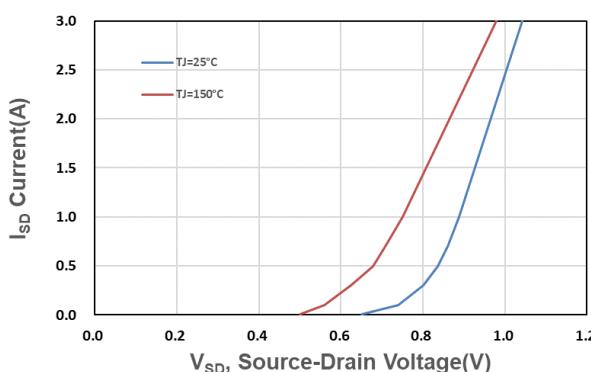
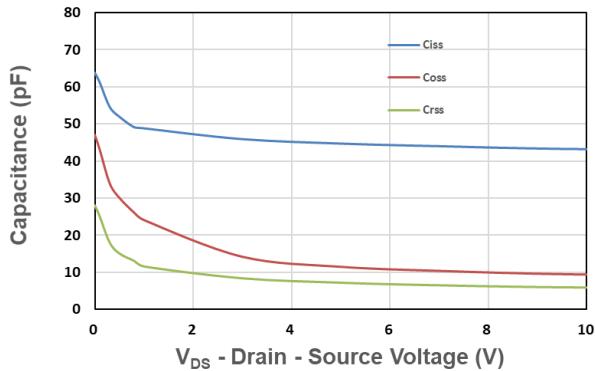
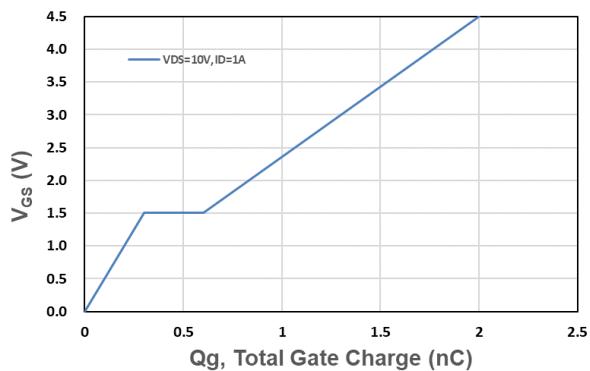
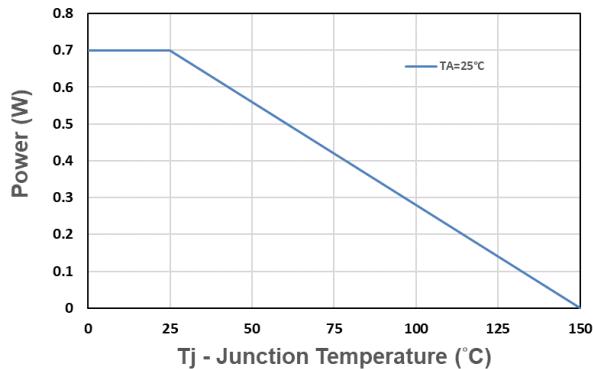
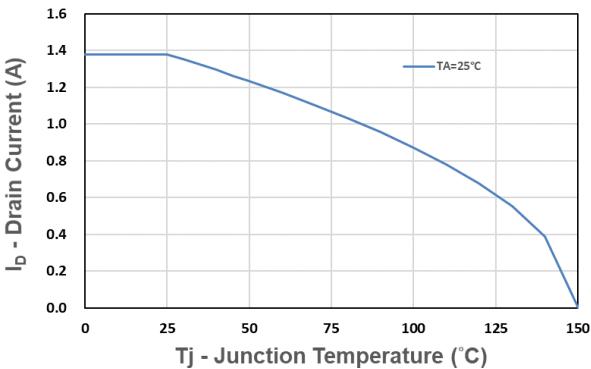
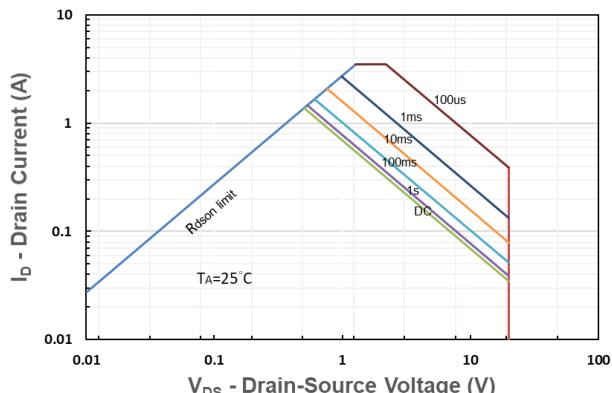
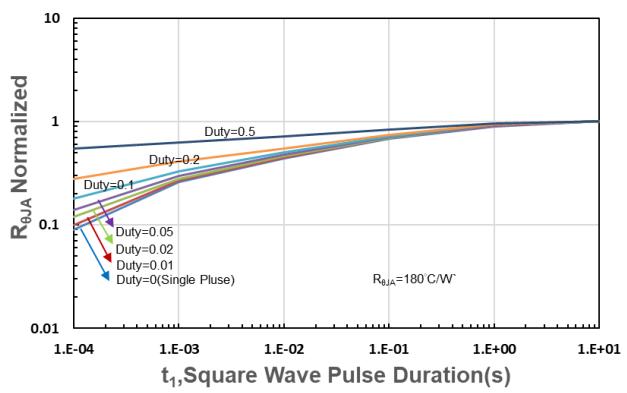
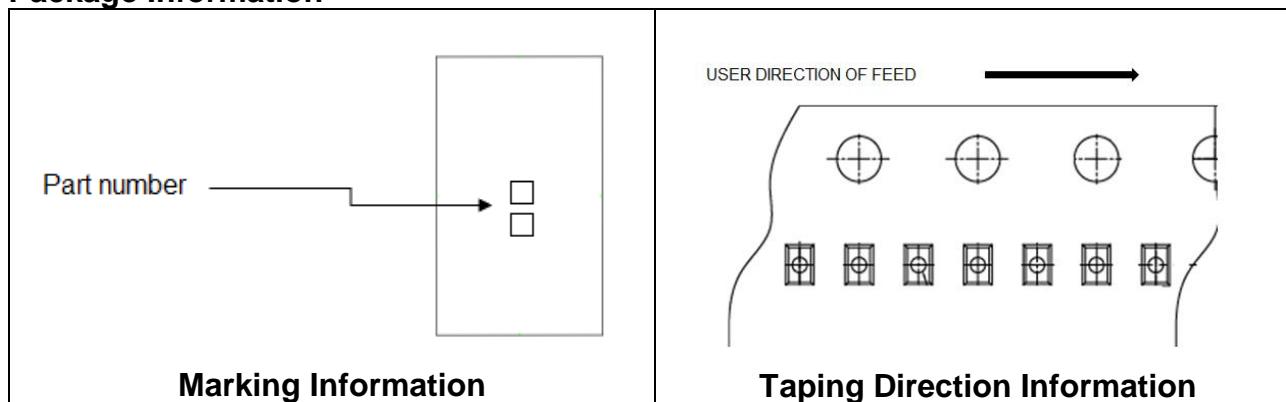


Figure 6. Source-Drain Diode Forward

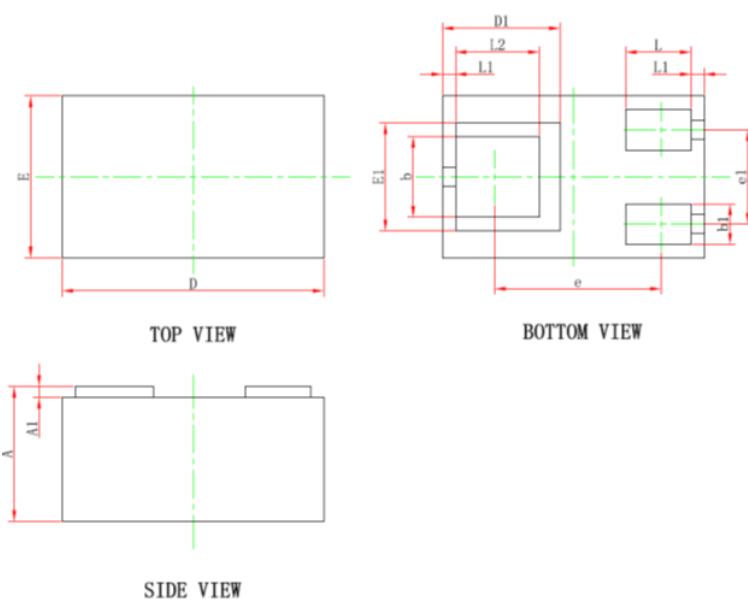

Figure 7. Capacitance

Figure 8. Gate Charge Characteristics

Figure 9. Power Dissipation

Figure 10. Drain Current

Figure 11. Safe Operating Area

Figure 12. $R_{\theta JA}$ Transient Thermal Impedance

Package Information



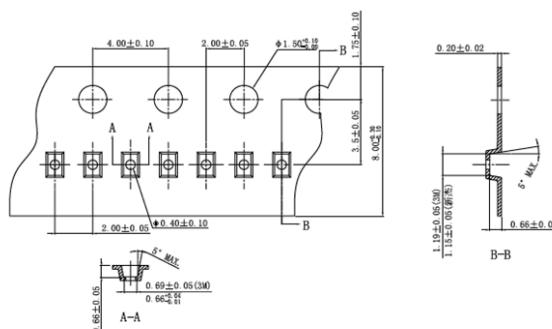
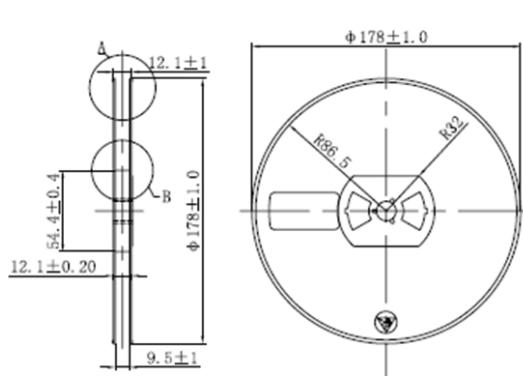
Marking Information

Taping Direction Information



COMMON DIMENSIONS		
UNITS: MILLIMETERS		
SYMBOL	MIN	MAX
A	0.45	0.55
A1	0.01	1.00
D	0.95	1.05
E	0.55	0.65
D1	0.45 RPF.	
E1	0.45 RPF.	
b	0.25	0.35
b1	0.10	0.20
e	0.635 RPF.	
e1	0.30	0.40
L	0.20	0.30
L1	0.05 RPF.	
L2	0.27	0.37

DFN1006 Dimension



Carrier Tape & Reel Dimension